

<b>INFORMATION DISCLOSURE STATEMENT</b>
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ATTY. DOCKET NUMBER LGC-0001-P SERIAL NUMBER NYA FILED 2-17-2004  
 FIRST INVENTOR: Se-Hwan Son TITLE ORGANIC THIN FILM TRANSISTOR

EXAMINER NYAART UNIT NYA

1. ☒ Applicant submits herewith a copy of (a) attached form PTO-1449, which lists all patents, publications, applications, or other information submitted for consideration by the Office; (b) a legible copy of each document required by 37 C.F.R. §1.98(b)(2).
2. ☐ Applicant herein apprises the Patent Office of references cited in a parent U.S. application from which this application obtains the benefit of an earlier filing date under 35 U.S.C. §120. The Serial Number of the parent application is U.S. Application \_\_\_\_\_ filed \_\_\_\_\_ and entitled \_\_\_\_\_.  
 The publications cited therein are listed on attached Form PTO-1449. In accordance with 37 C.F.R. §1.98(d) copies of the listed publications are not required. ☐ Additional parent patent applications are listed on an attached sheet.
3. ☐ In accordance with 37 C.F.R. §1.98(a)(3), Applicant hereby certifies that for each reference not in English (check at least one box below):  
☐ A copy of a translation of one or more non-English document, or portion thereof, is provided herewith;  
☐ A concise explanation is (check at least one box below):  
☐ provided in the accompanying foreign or international search report; ☐ incorporated into the specification; and/or ☐ provided herewith.

**37 C.F.R. §1.97(b)(1), (b)(2) – WITHIN 3 MONTHS OF FILING OR ENTRY IN NATIONAL STAGE**

4. ☒ Since this Information Disclosure Statement is being filed within three months of the filing date of the subject application or within three months of the date of entry of the national stage as set forth in 37 C.F.R. §1.491 in an international application, no fee or certification under 37 C.F.R. §1.97(e) is required.

**37 C.F.R. §1.97(b)(3), (b)(4) – PRIOR TO MAILING OF FIRST OFFICE ACTION OR FIRST ACTION AFTER REQUEST FOR CONTINUED EXAMINATION**


5. ☐ Since this Information Disclosure Statement is being filed before the mailing date of the first Office Action on the merits, or before the mailing of a first Office action after the filing of a request for continued examination under 37 C.F.R. §1.114, no fee or certification under 37 C.F.R. §1.97(e) is required.

**37 C.F.R. §1.97(c) – AFTER FIRST ACTION, BEFORE FINAL ACTION OR ALLOWANCE**

6. ☐ Since this Information Disclosure Statement is being filed outside of the period provided for in 37 C.F.R. §1.97(b), but before the mailing date of a Final Rejection or Notice of Allowance, this submission is being accompanied by (one of the following boxes must be checked):
- ☐ the fee required under 37 C.F.R. §1.97(c)(2) and specified in 37 C.F.R. §1.17(p).
  - ☐ the statement specified in 37 C.F.R. §1.97(e) (Box 8 or 9 must be checked).

**37 C.F.R. §1.97(d) – AFTER FINAL REJECTION OR ALLOWANCE**

7. ☐ Since this Information Disclosure Statement is being filed after the period specified in 37 C.F.R. §1.97(c), but on or before payment of the issue fee and is accompanied by both the statement specified in 37 C.F.R. §1.97(e) and the fee set forth in 37 C.F.R. §1.17(p). (Box 8 or 9 must be checked.)
8. ☐ In accordance with 37 C.F.R. §1.97(e)(1), Applicant's attorney certifies that each item of information contained in this Information Disclosure Statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this Information Disclosure Statement. ☐ The foreign or international search report(s) is/are enclosed.
9. ☐ In accordance with 37 C.F.R. §1.97(e)(2), Applicant's attorney certifies that no item of information contained in this Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing this certification after making reasonable inquiry, no item of information contained in this Information Disclosure Statement was known to any individual designated in 37 C.F.R. §1.56(c) more than three months prior to the filing of the information disclosure statement.
10. ☒ In the event the Commissioner of Patents deems that any additional fee is required under 37 C.F.R. §§ 1.16 or 1.17 in connection with this application, Applicant's attorneys authorize that such fee be charged to Deposit Account No. 06-1130.
11. Consideration of this Information Disclosure Statement is respectfully requested.

Name: <u>Soonja Bae</u>	Registration Number: <u>SEE ATTACHED</u>
Signature: 	Date: <u>February 17, 2004</u>

**CERTIFICATE OF MAILING OR TRANSMISSION:** I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner For Patents, P.O. Box 1450, Alexandria, VA 22313-1450, or [ ] facsimile transmitted to the U.S. Patent and Trademark Office to Facsimile No. \_\_\_\_\_ on the date shown below.

Name: _____	Date: _____
Signature: _____	Date: _____

<b>INFORMATION DISCLOSURE CITATION</b> <i>(Use several sheets if necessary)</i>	Docket Number (Optional) <b>LGC-0001-P</b>	Application Number <b>NYA</b>
	Applicant(s) <b>Se-Hwan Son, et al.</b>	
	Filing Date <b>2-17-2004</b>	Group Art Unit <b>NYA</b>

*EXAMINER INITIAL	OTHER DOCUMENTS <i>(Including Author, Title, Date, Pertinent Pages, Etc.)</i>
	ABSTRACT - "Contact dependence of <i>a</i> -sexithienyl thin-film transistor characteristics"; Authors: Lin, Y.Y., Gundlach, D.J., Jackson, T.N.; Materials Research Society Symposium Proceedings; 1996
	ABSTRACT - "Screen printed organic thin film transistor (OTFTs) on a flexible substrate"; Authors: Caprice Gray, Jianna Wang, Gregg Duthaler, Andrew Ritenour and Paul S. Drzaic; The International Society for Optical Engineering (SPIE); 2003
	"Organic electronics: Introduction"; Authors: J.M. Shaw and P.F. Seidler; International Business Machines Corp. (IBM) J. Res. & Dev., Vol. 45, No. 1; January 2001; Pgs. 3-9
	"Printing Process Suitable for Reel-to-Reel Production of High-Performance Organic Transistors and Circuits"; Authors: John A. Rogers, Zhenan Bao, Anita Makhija and Paul Braun; WILEY-VCH Verlag GmbH & Co.; Advanced Materials, Vol. 11, No. 9; 1999; Pgs. 741-745
	"Synthetic Chemistry for Ultrapure, Processable, and High-Mobility Organic Transistor Semiconductors"; Authors: Howard E. Katz, Zhenan Bao and Sylvain L Gilat; American Chemical Society; Accounts fo Chemical Research, Vol. 34, No. 5; 2001; Pgs. 359-369
	"Building Blocks for n-Type Organic Electronics: Regiochemically Modulated Inversion of Majority Carrier Sign in Perfluoroarene-Modified Polythiophene Semiconductors"; Authors: Antonio Facchetti, Myung-Han Yoon, Charlotte L. Stern, Howard E. Katz and Tobin J. Marks; Communications; WILEY-VCH Verlag GmbH & Co.; Angew. Chem. Int. Ed., Vol. 42; 2003; Pgs. 3900-3903
	"The Physical hemistry of Organic Field-Effect Transistors"; Authors: H.E. Katz and Z. Bao; FEATURE ARTICLE; American Chemical Society; J. Phys. Chem. B, Vol. 104, No. 4; 2000; Pgs. 671-678
	"New Air-Stable n-Channel Organic Thin Film Transistors"; Authors: Zhenan Bao, Andrew J. Lovinger and Janelle Brown; American Chemical Society; J. Am. Chem. Soc., Vol. 120, No. 1; 1998; Pgs. 207-208
EXAMINER	DATE CONSIDERED

\*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.